

MT41K256M16V80AWC1



Part Number: MT41K256M16V80AWC1

Manufacturer: Micron Technology

Description: IC DRAM 4G PARALLEL DIE

Data sheet:

RoHS Status: Lead free / RoHS Compliant

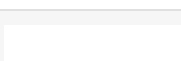
Ship From: Hong Kong

Shipment Way: DHL/Fedex/TNT/UPS/EMS

Images are for reference only.
See Product Specifications for product details.
Buy MT41K256M16V80AWC1 with confidence from
Component-World.HK, 1 Year Warranty

Request For Quotation

PRODUCT PARAMETER			
Part Number	MT41K256M16V80AWC1	Manufacturer	Micron Technology
Description	IC DRAM 4G PARALLEL DIE	Lead Free Status / RoHS Status	Lead free / RoHS Compliant
Quantity Available	7325 pcs	Data sheet	
Category	Integrated Circuits (ICs)	Write Cycle Time - Word, Page	-
Voltage - Supply	1.283 V ~ 1.45 V	Technology	SDRAM - DDR3L
Series	-	Operating Temperature	0°C ~ 95°C (TC)
Moisture Sensitivity Level (MSL)	3 (168 Hours)	Memory Type	Volatile
Memory Size	4Gb (256M x 16)	Memory Interface	Parallel
Memory Format	DRAM	Lead Free Status / RoHS Status	Lead free / RoHS Compliant
Detailed Description	SDRAM - DDR3L Memory IC 4Gb (256M x 16) Parallel		
Component-World.com is a Reliable Stocking Distributor of Electronic Components. We specialize in all Micron Technology series electronic components. We have 7325 pieces of Micron Technology MT41K256M16V80AWC1 in stock available now. Request a quote from electronics components distributor at Component-World.com, our sales team will contact you within 24 hours.			
RFQ Email: info@Components-World.com			

RELATED PRODUCTS			
	Part#: MT41K256M16TW-107 XIT:P TR Description: IC DRAM 4G PARALLEL 96FBGA	Manufacturers: Micron Technology	RFQ
	Part#: MT41K256M4JP-125:G Description: IC DRAM 1G PARALLEL 78FBGA	Manufacturers: Micron Technology	RFQ
	Part#: MT41K256M8DA-107 IT:K Description: IC DRAM 2G PARALLEL 933MHZ	Manufacturers: Micron Technology	RFQ
	Part#: MT41K256M16TW-107:P Description: IC DRAM 4G PARALLEL 96FBGA	Manufacturers: Micron Technology	RFQ
	Part#: MT41K256M16TW-107 M AIT:P TR Description: IC DRAM 4G PARALLEL 96FBGA	Manufacturers: Micron Technology	RFQ
	Part#: MT41K256M16TW-107 XIT:P Description: IC DRAM 4G PARALLEL 96FBGA	Manufacturers: Micron Technology	RFQ
	Part#: MT41K256M16V90BWC1 Description: IC DRAM 4G PARALLEL DIE	Manufacturers: Micron Technology	RFQ
	Part#: MT41K256M16TW-107 V:P TR Description: IC DRAM 4G PARALLEL 933MHZ	Manufacturers: Micron Technology	RFQ
	Part#: MT41K256M16TW-125:P Description: IC DRAM 4G PARALLEL 800MHZ	Manufacturers: Micron Technology	RFQ
	Part#: MT41K256M8DA-107 AAT:K TR Description: IC DRAM 2G PARALLEL 933MHZ	Manufacturers: Micron Technology	RFQ
	Part#: MT41K256M8DA-107 AAT:K Description: IC DRAM 2G PARALLEL 933MHZ	Manufacturers: Micron Technology	RFQ
	Part#: MT41K256M16TW-107:P TR Description: IC DRAM 4G PARALLEL 96FBGA	Manufacturers: Micron Technology	RFQ
	Part#: MT41K256M8DA-107 IT:K TR Description: IC DRAM 2G PARALLEL 933MHZ	Manufacturers: Micron Technology	RFQ
	Part#: MT41K256M4JP-15E:G TR Description: IC DRAM 1G PARALLEL 78FBGA	Manufacturers: Micron Technology	RFQ
	Part#: MT41K256M4DA-107:J TR Description: IC DRAM 1G PARALLEL 78FBGA	Manufacturers: Micron Technology	RFQ
	Part#: MT41K256M16V00HWC1-N001 Description: DDR3 4G DIE 256MX16	Manufacturers: Micron Technology	RFQ
	Part#: MT41K256M4JP-15E:G Description: IC DRAM 1G PARALLEL 78FBGA	Manufacturers: Micron Technology	RFQ
	Part#: MT41K256M16TW-107 V:P Description: IC DRAM 4G PARALLEL 933MHZ	Manufacturers: Micron Technology	RFQ
	Part#: MT41K256M16V00HWC1 Description: IC FLASH NAND 32GX8 TSOP	Manufacturers: Micron Technology	RFQ
	Part#: MT41K256M4DA-107:J Description: IC DRAM 1G PARALLEL 78FBGA	Manufacturers: Micron Technology	RFQ

Related keywords for MT41K256M16V80AWC1			
Micron Technology MT41K256M16V80AWC1	MT41K256M16V80AWC1 distributor	MT41K256M16V80AWC1 supplier	MT41K256M16V80AWC1 price
MT41K256M16V80AWC1 download datasheet	MT41K256M16V80AWC1 datasheet	MT41K256M16V80AWC1 stock	buy MT41K256M16V80AWC1
Micron Technology MT41K256M16V80AWC1	Micron Technology Inc. MT41K256M16V80AWC1		